June 2007

FAIRCHILD

SEMICONDUCTOR

FFPF04H60S Hyperfast 2 Rectifier

Features

- High Speed Switching, $t_{rr} < 45$ ns
- High Reverse Voltage and High Reliability
- Low Forward Voltage, $V_F < 2.1V @ 4A$
- RoHS compliant
- Applications
- General Purpose
- Switching Mode Power Supply
- Free-wheeling diode for motor application
- Power switching circuits

Pin Assignments

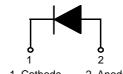


The FFPF04H60S is a hyperfast 2 rectifier and silicon nitride passivated ion-implanted epitaxial planar construction.

4A, 600V Hyperfast 2 Rectifier

This device is intended for use as freewheeling/clamping rectifiers in a variety of switching power supplies and other power switching applications. Its low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.





1. Cathode 2. Anode

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Absolute Maximum Ratings T_C = 25°C unless otherwise noted*

Symbol	Parameter		Value	Units
V _{RRM}	Peak Repetitive Reverse Voltage		600	V
V _{RWM}	Working Peak Reverse Voltage		600	V
V _R	DC Blocking Voltage		600	V
I _{F(AV)}	Average Rectified Forward Current @ To	_c = 115 ^o C	4	А
I _{FSM}	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave		40	А
T _J , T _{STG}	Operating Junction and Storage Temperature		-65 to +150	°C
Drain current li	nited by maximum junction temperature			

Thermal Characteristics

Symbol	Parameter	Ratings	Units
$R_{\theta JC}$	Maximum Thermal Resistance, Junction to Case	6.2	°C/W

Package Marking

Γ	Device Marking	Device	Package	Reel Size	Tape Width	Quantity
	F04H60S	FFPF04H60STU	TO-220F	-	-	50

Parameter	Condition	Min.	Тур.	Max.	Units	
v 1	I _F = 4A	$T_{C} = 25^{\circ}C$ $T_{C} = 125^{\circ}C$	-	-	2.1	V
V _{FM} ¹	$I_F = 4A$	$T_{C} = 125^{\circ}C$	-	-	1.7	V
ı 1	V _R = 600V	$T_{C} = 25^{\circ}C$	-	-	100	μA
I _{RM} '	$V_{R} = 600V$	$T_{C} = 125^{\circ}C$	-	-	200	μA
	I _F = 1A, di/dt = 100A/μs, V _{CC} = 30V	$T_{C} = 25^{\circ}C$ $T_{C} = 25^{\circ}C$	-	21	35	ns
۲r	$I_F = 4A$, di/dt = 100A/µs, $V_{CC} = 390V$	$T_C = 25^{\circ}C$	-	33	45	ns
I _{rr}		$T_{\rm C} = 25^{\rm o}{\rm C}$	-	1.9	-	Α
ı _{rr} Q _{rr}	$I_{F} = 4A, di/dt = 100A/\mu s, V_{CC} = 390V$		-	31	-	nC
W _{AVL}	Avalanche Energy (L = 40mH)		4	-	-	mJ

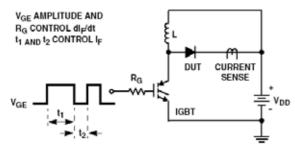
Notes: 1: Pulse: Test Pulse width = 300µs, Duty Cycle = 2%

 $Q_1 = IGBT (BV_{CES} > DUT V_{R(AVL)})$

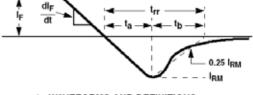
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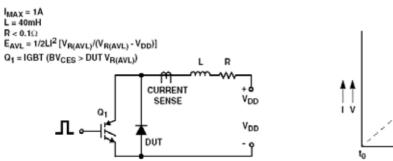
Test Circuit and Waveforms



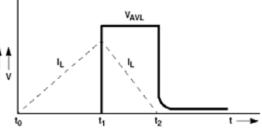
trr TEST CIRCUIT



trr WAVEFORMS AND DEFINITIONS

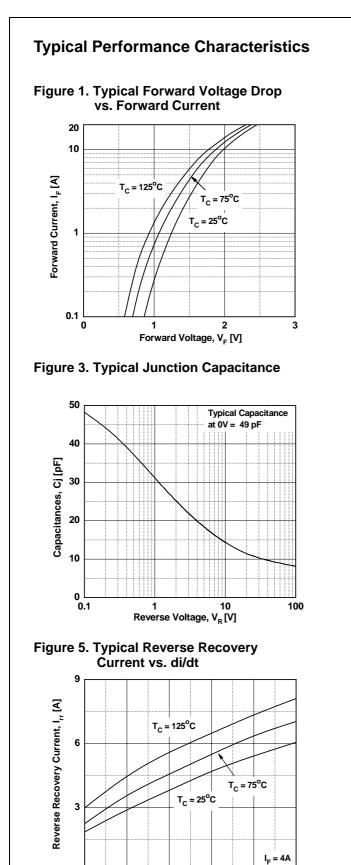


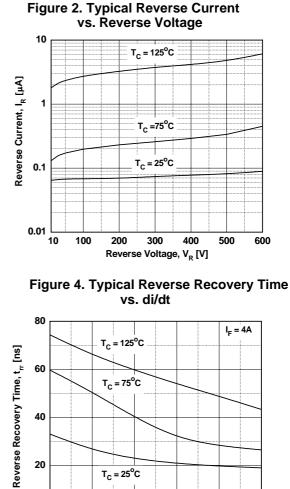
AVALANCHE ENERGY TEST CIRCUIT

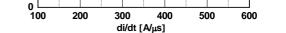


AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

FFPF04H60S Hyperfast 2 Rectifier

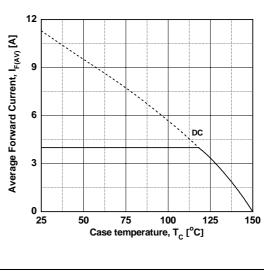






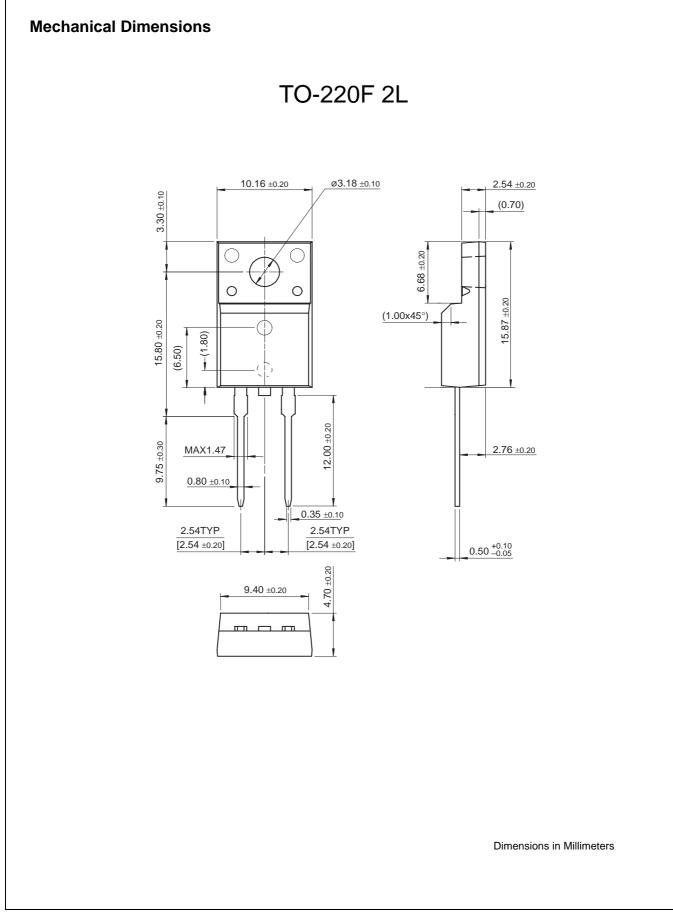
 $T_{C} = 25^{\circ}C$

Figure 6. Forward Current Derating Curve



FFPF04H60S Rev. A

di/dt [A/µs]



FFPF04H60S Hyperfast 2 Rectifier



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